## **Supporting Information**

Rationally designed carbon-encapsulated manganese selenides composites from metal-organic frameworks for stable aqueous aqueous Zn-Mn batteries

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## **S1. CALCULATION EQUATIONS**

During the electrochemical kinetic analysis-based CV curves, the peak current (*i*) and scan rate (v) can be obeyed with Equations. 1-2<sup>1, 2</sup>:

$$i = av^b$$
 1

$$\log(i) = b \log(v) + \log(a)$$

where *a* and *b* are the fitted parameters. The current i(V) at a given potential *V* obey the relations of <sup>3</sup>

$$i(V) = k_1 v + k_2 v^{1/2}$$
3

and

$$i(V)/v^{1/2} = k_1/v^{1/2} + k_2$$

Where i(V),  $k_1v$ , and  $k_2v^{1/2}$  correspond to the measured current, current from the surface capacitive contribution, and current from diffusion-controlled  $Zn^{2+}$  intercalation contribution, respectively.

The ions diffusion coefficient can be well calculated from the low-frequency plots using the following equation (5):

$$D = \frac{R^2 T^2}{2A^2 n^4 F^4 C^2 \sigma^2}$$
 5

where R is the gas constant, T is the absolute temperature, A is the surface area of electrode, n is the number of electrons per molecule during oxidization, F is the Faraday constant, C is the concentration of ion, and  $\sigma$  is the Warburg factor, where the Warburg factor is related to Z' derived by the following equation (6)<sup>4</sup>:

$$Z' = R_s + R_{ct} + \sigma \omega^{-1/2}$$

Where  $\omega$  is the angular frequency in the region,  $R_s$  is the ohmic resistance,  $R_{ct}$  is the charge-transfer resistance.

The ions diffusion coefficients were also measured by Galvanostatic Intermittent Titration Technique (GITT) and calculated based on the equation (7) below<sup>5</sup>:

$$D_{GITT} = \frac{4}{\pi \tau} \left( \frac{m_B V_m}{M_B S} \right)^2 \left( \frac{\Delta E_s}{\Delta E_\tau} \right)^2$$

$$7$$

Where  $m_B$  (g) is the weight of the active materials,  $M_B$  (g mol<sup>-1</sup>) is the molecular weight,  $V_m$  (cm<sup>3</sup> mol<sup>-1</sup>) is its molar volume, S (cm<sup>2</sup>) is the surface area,  $\tau$  (s) is duration time of the current pulse,  $\Delta E_s$  is the voltage difference measured at the end of the relaxation period for two successive steps,  $\Delta E_{\tau}$  is the difference between the initial voltage and final voltage during the discharge pulse time  $\tau$  after eliminating the iR drop. It is also calculated  $D_{GITT}$  by equation (8) as follows<sup>6</sup>:

$$D_{GITT} = \frac{4L^2}{\pi\tau} \left(\frac{\Delta E_s}{\Delta E_\tau}\right)^2$$
8

L is ion diffusion length (cm), for compact electrode, it is equal to the thickness of cathode material.

## S2. Results



Figure S1. XRD spectrum for (a) MIL-100, MIL-GO-*x* and (b) GO.



Figure S2. SEM images with different magnifications of GO, respectively. (a) 5  $\mu$ m, (b) 1  $\mu$ m, (c) 500 nm.



Figure S3. SEM images with different magnifications of MIL-100, respectively. (a) 5  $\mu$ m, (b) 1  $\mu$ m, (c) 200 nm.



Figure S4. SEM images with different magnifications of MIL@GO-2, respectively. (a)  $5 \mu m$ , (b)  $1 \mu m$ , (c) 200 nm.



Figure S5. SEM images with different magnifications of MIL@GO-4, respectively. (a)  $5 \mu m$ , (b)  $1 \mu m$ , (c) 200 nm.



**Figure S6.** SEM images with different magnifications of MIL@GO-6, respectively. (a)  $5 \mu m$ , (b)  $1 \mu m$ , (c) 200 nm.



Figure S7. (a)  $N_2$  adsorption-desorption isotherms and (b) pore size distributions of MIL-100 and C@MnSe@GO-2.

Figure S7 shows the N<sub>2</sub> adsorption and desorption curves of MIL-100 and C@MnSe@GO-2 and the corresponding pore size distributions. It can be seen in Figure S7a that all curves exhibit H3-type with hysteresis loops. MIL-100 exhibits a large specific surface area of about 500.86 m<sup>2</sup> g<sup>-1</sup>, whereas the specific surface area of C@MnSe@GO-2 decreases slightly from 500.86 m<sup>2</sup> g<sup>-1</sup> to 453.12 m<sup>2</sup> g<sup>-1</sup> after the introduction of GO. However, owing to the high-temperature gas-phase selenization process, a carbon coating is formed on the surface of C@MnSe@GO-2. This carbon coating serves to increase the material's pore volume and pore size, providing additional reactive sites for zinc ions. As a result, the enhanced porosity contributes to the improved reactivity and facilitates a higher capacity for zinc ion reactions.

_	Samples	$S_{\rm BET} ({ m m}^2 { m g}^{-1})$	$V_{\rm total}({ m cm^3}$	Average pore
			<b>g</b> <sup>-1</sup> )	size (nm)
	MIL-100	500.86	0.23	1.82
	MnSe@GO-2	453.12	0.33	2.90

**Table S1.** The porous structure for MIL-100 and C@MnSe@GO-2.

 $S_{\text{BET}}$ : BET surface area,  $V_{\text{total}}$ : total pore volume calculated by density functional theory (DFT) method.



Figure S8. TGA curve of the C@MnSe@GO-2 and MIL-100@GO-2.



Figure S9. the O 1s high-resolution spectra of C@MnSe@GO-2



Figure S10. survey XPS spectrum of C@MnSe@GO-4 and C@MnSe@GO-6.

**Table S2.** The chemical compositions and contents of the C@MnSe@GO-x fromXPS analysis.

Samples	C (at%)	Se (at%)	O (at%)	Mn (at%)
Binding energy (eV)	~284	~54	~532	~641/653
C@MnSe@GO-2	61.87	6.29	26.97	4.87
C@MnSe@GO-4	90.16	6.49	2.14	1.21
C@MnSe@GO-6	90.37	6.33	2.11	1.19



Figure S11. SEM images with different magnifications of Bulk  $MnO_2$ , respectively. (a) 1  $\mu$ m, (b) 500 nm, (c) 200 nm.



Figure S12. The galvanostatic charge-discharge curves for C@MnSe@GO-x.



Figure S13. Cycling performance at 100 mA g-1 for C@MnSe@GO-2.



Figure S14. HRTEM images after Cycle test at 100 mA g<sup>-1</sup> for C@MnSe@GO-2.



Figure S15. XPS images after Cycle test at 100 mA g<sup>-1</sup> for C@MnSe@GO-2, (a) XPS survey, (b) O 1s.

Samples	R <sub>s</sub> (ohm)	R <sub>ct</sub> (ohm)		
Bulk MnO <sub>2</sub>	3.14	623.24		
C@MnSe@GO-0	2.97	52.5		
C@MnSe@GO-2	2.58	32.2		

Table S3  $R_s$  and  $R_{ct}$  values fitted from the corresponding EIS plots.

**Table S4** *b* values fitted from the corresponding log(i) versus log(v) plots.

Samples	Anodic peak	Cathodic peak 1	Cathodic peak 2
C@MnSe@GO-0	y = 0.84 x - 0.14	y = 0.91x - 0.65	y = 0.88x - 0.48
C@MnSe@GO-2	y = 0.94x + 0.11	y = 0.72x - 0.54	y = 0.91x - 0.20



Figure S16. GITT and ionic diffusion coefficient curves during discharging for C@MnSe@GO-0.

Materials	Voltage window (V)	Electrolyte	Current density	Specific capacity (mAh g <sup>-</sup>	Current density	Specific capacity (mAh g <sup>-</sup>	Ref
		_		1)		1)	
Se-in-	0.1-2.1	4 m	200 mA	664.7	10000	430.6	7
$Cu[Co(CN)_6]$		$Zn(OTf)_2$	g-1	<b>.</b>	$mA g^{-1}$	101	0
MnS-EDO	0.8-2.0	2M	300 mA	335.7	3000	104	8
		$ZnSO_4/0.1$	g-1		$mA g^{-1}$		
		M MnSO <sub>4</sub>					
MnS0.5Se0.5	0.8-1.85	2M	100 mA	272.8	2000	91.8	9
		$ZnSO_4/0.2$	g-1		mA g <sup>-1</sup>		
		$M MnSO_4$	100	40-	• • • • •	100	10
$VS_2$	0.4-1.0	1M ZnSO <sub>4</sub>	100 mA	187	2000	133	10
			g <sup>-1</sup>		$mA g^{-1}$		
MnS	0.8-2.0	2M	90 mA g⁻	297.7	3000	36.6	11
		ZnSO <sub>4</sub> /0.1	1		mA g <sup>-1</sup>		
		M MnSO <sub>4</sub>		• • • •			
MnSe@rGO	0.8-1.85	2M	0.1 C	290	5 C	178	12
		$ZnSO_4/0.1$					
		M MnSO <sub>4</sub>				- ·	
$MnSe_2$	0.8-1.85	2M	100 mA	452.4	2000	242.7	13
		ZnSO <sub>4</sub> /0.1	g-1		mA g <sup>-1</sup>		
		M MnSO <sub>4</sub>	100	• • • •	10000		
MnSe-EO	0.7-1.9		100 mA	309	10000	125.9	14
		$ZnSO_4/0.1$	g-1		mA g <sup>-1</sup>		
		M MnSO <sub>4</sub>					
MoSSe/rGO	0.3-1.3	2M	200 mA	253.8	5000	124.2	15
		$Zn(CF_3SO_3)_2$	g-1		$mA g^{-1}$		
MnS/MnO@N-	0.8-1.9	2M	100 mA	257.8	2000	128.7	16
CF		ZnSO4/0.1	g-1		mA g <sup>-1</sup>		
	0.4.6	$M MnSO_4$				100 (	. –
Layered VSe <sub>2</sub>	0-1.6	2M ZnSO <sub>4</sub>	200 mA	250.6	5000	132.6	17
			g-1		$mA g^{-1}$		10
$rGO-VSe_2$	0.2-1.4	$2M ZnSO_4$	500 mA	221.5	4000	161	18
	0 0 <b>0</b> 0	2) (	g-1		$mA g^{-1}$	10(0	10
$MnSe_2/CNTs$	0.8-2.0	2M	100 mA	451.1	3000	126.3	19
		$ZnSO_4/0.1$	g-1		mA g <sup>-1</sup>		
	0.4.1.6	$M MnSO_4$	••••	0.41.0	1000	0001	•
$VSe_{2-x}-SS$	0.4-1.6	3M	200 mA	241.2	4000	230.1	20
N/G	0 4 1 6	$Zn(CF_3SO_3)_2$	g-1	121.0	$mA g^{-1}$	70 5	01
$VSe_2$	0.4-1.6	2M ZnSO <sub>4</sub>	100 mA	131.8	2000	/9.5	21
	0.0.1.07	23.6	g <sup>-1</sup>	450.01	$mA g^{-1}$	202 (7	<b>T</b> 1 ·
C(a) vin Se(a) GO-	0.8-1.85	2M	100 mA	439.81	2000	283.67	I his
2		$2nSO_4/0.2$	g-1		mA g <sup>-1</sup>		work
		M MnSO <sub>4</sub>					

 Table S5 Comparison of the Zn ion storage performance of C@MnSe@GO-2 and other recently reported similar Zn-ion battery cathodes.

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